

## PALM INTRANET

Day: Monday Date: 2/27/2006

Time: 10:50:38

### **Inventor Name Search Result**

Your Search was:

Last Name = KIYOKU First Name = HIROYUKI

Application#	Patent#	Status	Date Filed	Title	Inventor Name
08565101	5777350	150		NITRIDE SEMICONDUCTOR LIGHT-EMITȚING DEVICE	KIYOKU, HIROYUKI
09069240	Not Issued	164		NITRIDE SEMICONDUCTOR LIGHT-EMITTING DEVICE	KIYOKU, HIROYUKI
09202141	6153010	150	12/09/1998	METHOD OF GROWING NITRIDE SEMICONDUCTORS, NITRIDE SEMICONDUCTOR SUBSTRATE AND NITRIDE SEMICONDUCTOR DEVICE	KIYOKU, HIROYUKI
09370170	Not Issued	164		NITRIDE SEMICONDUCTOR LIGHT-EMITTING DEVICE	KIYOKU, HIROYUKI
09603437	Not Issued	168	06/23/2000	Nitride semiconductor growth method, nitride semiconductor substrate, and nitride semiconductor device	KIYOKU, HIROYUKI
09809038	6900465	150	03/16/2001	NITRIDE SEMICONDUCTOR LIGHT-EMITTING DEVICE	KIYOKU, HIROYUKI
09880843	6627974	150	06/15/2001	NITRIDE SEMICONDUCTOR SUBSTRATE AND METHOD FOR MANUFACTURING THE SAME, AND NITRIDE SEMICONDUCTOR DEVICE USING NITRIDE SEMICONDUCTOR SEMICONDUCTOR	KIYOKU, HIROYUKI
<u>09973817</u>	6580099	150		NITRIDE SEMICONDUCTOR LIGHT-EMITTING DEVICE	KIYOKU, HIROYUKI
09986332	Not Issued	71	1	Nitride semiconductor growth method, nitride semiconductor substrate, and nitride semiconductor device	KIYOKU, HIROYUKI
10260442	6627520	150	10/01/2002	NITRIDE SEMICONDUCTOR SUBSTRATE AND METHOD	KIYOKU, HIROYUKI

•				(	
				FOR MANUFACTURING THE SAME, AND NIVRIDE SEMICONDUCTOR DEVICE USING NITRIDE SEMICONDUCTOR SUBSTRATE	
10261487	6756611	150	10/02/2002	NITRIDE SEMICONDUCTOR GROWTH METHOD, NITRIDE SEMICONDUCTOR SUBSTRATE, AND NITRIDE SEMICONDUCTOR DEVICE	KIYOKU, HIROYUKI
10389806	6861729	150	03/18/2003	NITRIDE SEMICONDUCTOR SUBSTRATE AND METHOD FOR MANUFACTURING THE SAME, AND NITRIDE SEMICONDUCTOR DEVICE USING NITRIDE SEMICONDUCTOR SUBSTRATE	KIYOKU, HIROYUKI
10600833	6940103	150	06/23/2003	NITRIDE SEMICONDUCTOR GROWTH METHOD, NITRIDE SEMICONDUCTOR SUBSTRATE AND NITRIDE SEMICONDUCTOR DEVICE	KIYOKU, HIROYUKI
11052835	Not Issued	41	02/09/2005	Nitride semiconductor growth method, nitride semiconductor substrate, and nitride semiconductor device	KIYOKU, HIROYUKI

Soarch Another Inventor	Last Name	First Name	
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### **Inventor Name Search Result**

Your Search was:

Last Name = NAKAMURA

First Name = SHUJI

Dotont	Status	Doto Eiled	Title	Inventor Name
4288714	150	06/06/1979	1	NAKAMURA, SHUJI
4483191	150	10/14/1982	_	NAKAMURA, SHUJI
4572572	150	04/11/1984	•	NAKAMURA, SHUJI
4890103	250	04/30/1985		NAKAMURA, SHUJI
4682171	150	04/30/1985	TURN-AND-BANK INDICATOR WHICH DISPLAYS THE TOTAL ANGLE OR TOTAL TIME OF A TURN.	NAKAMURA, SHUJI
4687832	150			NAKAMURA, SHUЛ
Not Issued	161	05/22/1987	THERMOSETTING EPOXY RESIN COMPOSITION	NAKAMURA, SHUЛ
Not Issued	161	03/30/1988	ANTI-TUMOR CELL SURFACE GANGLIOSIDE- SPECIFIC MONOCLONAL ANTIBODY AND HYBRIDOMA PRODUCING THE SAME	NAKAMURA, SHUJI
5106731			ENDOTHELIAL CELLS AND GROWTH FACTOR	NAKAMURA, SHUJI
4941696	150	03/14/1989	DOOR LOCK DEVICE FOR VEHICLE	NAKAMURA, SHUЛ
<u>4981313</u>	150	1 1		1 1
	4288714 4483191 4572572 4890103 4682171 4687832 Not Issued Not Issued 5106731	4288714   150	4288714       150       06/06/1979         4483191       150       10/14/1982         4572572       150       04/11/1984         4890103       250       04/30/1985         4682171       150       04/30/1985         Not Issued       161       05/22/1987         Not Issued       161       03/30/1988         150       10/21/1988         4941696       150       03/14/1989         4981313       150       03/28/1989	150   06/06/1979   SPARK PLUG FOR INTERNAL COMBUSTION ENGINE     4483191   150   10/14/1982   AIRSPEED INDICATOR FOR LOW-SPEED CONVEYANCES     4572572   150   04/11/1984   LOCKING DEVICE OF HOOD FOR VENTILATOR WINDOW IN AUTOMOBILE     4890103   250   04/30/1985   RATE-OF-CLIMB INDICATOR     4682171   150   04/30/1985   TURN-AND-BANK INDICATOR WHICH DISPLAYS THE TOTAL ANGLE OR TOTAL TIME OF A TURN.     4687832   150   12/30/1985   NOVEL EPOXY RESIN COMPOSITIONS     Not Issued   161   05/22/1987   THERMOSETTING EPOXY RESIN COMPOSITION     Not Issued   161   03/30/1988   ANTI-TUMOR CELL SURFACE GANGLIOSIDE-SPECIFIC MONOCLONAL ANTIBODY AND HYBRIDOMA PRODUCING THE SAME     5106731   150   10/21/1988   KAPOSI'S SARCOMA ENDOTHELIAL CELLS AND GROWTH FACTOR     4941696   150   03/14/1989   DOOR LOCK DEVICE FOR VEHICLE

07329609	4921286	150	03/28/1989	LOCK DEVICE FOR USE OF VEHICLE DOORS	NAKAMURA, SHUJI
07502141	Not Issued	161	03/29/1990	MONOCLONAL ANTIBODIES THAT DEFINE ONCOSTATIN M TO INHIBIT GROWTH OF KAPOSI'S SARCOMA	NAKAMURA, SHUJI
07550985	Not Issued	161	07/11/1990	PROCESS FOR PRODUCING TETRAEPOXY RESINS, EPOXY RESIN COMPOSITIONS, TETRAEPOXY RESINS AND TETRAHYDRIC PHENOL COMPOUNDS	NAKAMURA, SHUJI
07761142	5156424	150	09/17/1991	VEHICULAR LOCK DEVICE	NAKAMURA, SHUЛ
07780469	5334277	150	10/22/1991	METHOD OF VAPOR- GROWING SEMICONDUCTOR CRYSTAL AND APPARATUS FOR VAPOR- GROWING THE SAME	NAKAMURA, SHUJI
07810420	Not Issued	161	12/20/1991	METHOD FOR TREATING KAPOSI"S SARCOMA AND BLOCKING OR INHIBITING VASCULAR PERMEABILITY	NAKAMURA, SHUJI
07826997	5290393	150	01/28/1992	CRYSTAL GROWTH METHOD FOR GALLIUM NITRIDE-BASED COMPOUND SEMICONDUCTOR	NAKAMURA, SHUJI
07834084	5180198	150		MOTOR DRIVEN LOCK DEVICE FOR TRUNK LID AND THE LIKE	NAKAMURA, SHUJI
07965544	Not Issued	124	10/23/1992	MONOCLONAL ANTIBODIES THAT DEFINE ONCOSTATIN M TO INHIBIT GROWTH OF KAPOSI'S SARCOMA	NAKAMURA, SHUJI
07970145	5306662	150	11/02/1992	METHOD OF MANUFACTURING P-TYPE COMPOUND SEMICONDUCTOR	NAKAMURA, SHUJI
08153153	5578839	150	11/17/1993	LIGHT-EMITTING GALLIUM NITRIDE-BASED COMPOUND SEMICONDUCTOR DEVICE	NAKAMURA, SHUJI
08180326	5468678	150	01/12/1994	METHOD OF MANUFACTURING P-TYPE COMPOUND SEMICONDUCTOR	NAKAMURA, SHUJI

08223739	5433169	150	04/06/1994	METHOD OF DEPOSITING A GALLIUM NITRIDE-BASED III-V GROUP COMPOUND SEMICONDUCTOR CRYSTAL LAYER	NAKAMURA, SHUJI
08234001	5563422	150	04/28/1994	GALLIUM NITRIDE-BASED III-V GROUP COMPOUND SEMICONDUCTOR DEVICE AND METHOD OF PRODUCING THE SAME	NAKAMURA, SHUJI
08336612	5518999	150	11/09/1994	METHOD FOR TREATING KAPOSI'S SARCOMA AND BLOCKING OR INHIBITING VASCULAR PERMEABILITY	NAKAMURA, SHUJI
08565101	5777350	150	11/30/1995	NITRIDE SEMICONDUCTOR LIGHT-EMITTING DEVICE	NAKAMURA, SHUJI
08661138	5747832	150	06/10/1996	LIGHT-EMITTING GALLIUM NITRIDE-BASED COMPOUND SEMICONDUCTOR DEVICE	NAKAMURA, SHUJI
08661157	5734182	150	06/10/1996	LIGHT-EMITTING GALLIUM NITRIDE-BASED COMPOUND SEMICONDUCTOR DEVICE	NAKAMURA, SHUJI
08665759	5652434	150	06/17/1996	GALLIUM NITRIDE-BASED III-V GROUP COMPOUND SEMICONDUCTOR	NAKAMURA, SHUJI
08670242	5767581	150	06/17/1996	GALLIUM NITRIDE-BASED III-V GROUP COMPOUND SEMICONDUCTOR	NAKAMURA, SHUJI
08705972	5880486	150		LIGHT-EMITTING GALLIUM NITRIDE-BASED COMPOUND SEMICONDUCTOR DEVICE	NAKAMURA, SHUJI
08743729	5959307	150	11/06/1996	NITRIDE SEMICONDUCTOR DEVICE	NAKAMURA, SHUJI
08995167	5877558	150	12/19/1997	GALLIUM NITRIDE-BASED III-V GROUP COMPOUND SEMICONDUCTOR	NAKAMURA, SHUJI
09004925	6172382	150	11	NITRIDE SEMICONDUCTOR LIGHT-EMITTING AND LIGHT-RECEIVING DEVICES	NAKAMURA, SHUJI
09063778	Not Issued	95	04/22/1998	HEDGEHOG PROTEIN	NAKAMURA, SHUJI
09069240	Not Issued	164	II I	NITRIDE SEMICONDUCTOR LIGHT-EMITTING DEVICE	NAKAMURA, SHUJI
<u>09145972</u>	6078063	150	II I	LIGHT-EMITTING GALLIUM NITRIDE-BASED COMPOUND	NAKAMURA, SHUJI

				SEMICONDUCTOR DEVICE	
09202141	6153010	150	12/09/1998	METHOD OF GROWING NITRIDE SEMICONDUCTORS, NITRIDE SEMICONDUCTOR SUBSTRATE AND NITRIDE SEMICONDUCTOR DEVICE	NAKAMURA, SHUJI
<u>09209826</u>	6093965	150	12/11/1998	GALLIUM NITRIDE-BASED III-V GROUP COMPOUND SEMICONDUCTOR	NAKAMURA, SHUЛ
09273455	6677930	150	03/22/1999	MOUSE	NAKAMURA, SHUJI
09293060	Not Issued	164	04/25/2000	NITRIDE SEMICONDUCTOR DEVICE	NAKAMURA, SHUJI
09300788	6215133	150	04/28/1999	LIGHT-EMITTING GALLIUM NITRIDE-BASED COMPOUND SEMICONDUCTOR DEVICE	NAKAMURA, SHUJI
09370170	Not Issued	164	08/09/1999	NITRIDE SEMICONDUCTOR LIGHT-EMITTING DEVICE	NAKAMURA, SHUЛ
09448479	6204512	150	11/24/1999	GALLIUM NITRIDE-BASED III-V GROUP COMPOUND SEMICONDUCTOR DEVICE AND METHOD OF PRODUCING THE SAME	NAKAMURA, SHUJI
09450592	6512344	150	11/30/1999	CONTROL APPARATUS EQUIPPED WITH BACK DRIVE	NAKAMURA, SHUJI
09463643	Not Issued	93	05/01/2000	NITRIDE SEMICONDUCTOR DEVICE	NAKAMURA, SHUJI
09478799	Not Issued	71	51 I		NAKAMURA, SHUJI
09500288	6835956	150	02/08/2000	NITRIDE SEMICONDUCTOR DEVICE AND MANUFACTURING METHOD THEREOF	NAKAMURA, SHUJI
09516193	6469323	150	03/01/2000	LIGHT-EMITTING GALLIUM NITRIDE-BASED COMPOUND SEMICONDUCTOR DEVICE	NAKAMURA, SHUJI

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### **Inventor Name Search Result**

Your Search was:

Last Name = KOZAKI First Name = TOKUYA

Application#	Patent#	Status	Date Filed	Title	Inventor Name
09202141	6153010			METHOD OF GROWING NITRIDE SEMICONDUCTORS, NITRIDE SEMICONDUCTOR SUBSTRATE AND NITRIDE SEMICONDUCTOR DEVICE	KOZAKI, TOKUYA
09519440	6711191	150		NITRIDE SEMICONDUCTOR LASER DEVICE	KOZAKI, TOKUYA
09603437	Not Issued	168	06/23/2000	Nitride semiconductor growth method, nitride semiconductor substrate, and nitride semiconductor device	KOZAKI, TOKUYA
09880843	6627974	150	06/15/2001	NITRIDE SEMICONDUCTOR SUBSTRATE AND METHOD FOR MANUFACTURING THE SAME, AND NITRIDE SEMICONDUCTOR DEVICE USING NITRIDE SEMICONDUCTOR SUBSTRATE	KOZAKI, TOKUYA
09898460	6586762	150	07/05/2001	NITRIDE SEMICONDUCTOR DEVICE WITH IMPROVED LIFETIME AND HIGH OUTPUT POWER	KOZAKI, TOKUYA
09986332	Not Issued	71	11/08/2001	Nitride semiconductor growth method, nitride semiconductor substrate, and nitride semiconductor device	KOZAKI, TOKUYA
10260442	6627520	150	10/01/2002	NITRIDE SEMICONDUCTOR SUBSTRATE AND METHOD FOR MANUFACTURING THE SAME, AND NITRIDE SEMICONDUCTOR DEVICE USING NITRIDE SEMICONDUCTOR	KOZAKI, TOKUYA

		! I		SUBSTRATE	ı İ
10261487	6756611	150	10/02/2002	NITRIDE SEMICONDUCTOR GROWTH METHOD, NITRIDE SEMICONDUCTOR SUBSTRATE, AND NITRIDE SEMICONDUCTOR DEVICE	KOZAKI, TOKUYA
10389806	6861729	150	03/18/2003	NITRIDE SEMICONDUCTOR SUBSTRATE AND METHOD FOR MANUFACTURING THE SAME, AND NITRIDE SEMICONDUCTOR DEVICE USING NITRIDE SEMICONDUCTOR SUBSTRATE	KOZAKI, TOKUYA
10443083	6838693	150	05/22/2003	NITRIDE SEMICONDUCTOR DEVICE	KOZAKI, TOKUYA
10600833	6940103	150	06/23/2003	NITRIDE SEMICONDUCTOR GROWTH METHOD, NITRIDE SEMICONDUCTOR SUBSTRATE AND NITRIDE SEMICONDUCTOR DEVICE	KOZAKI, TOKUYA
10700270	Not Issued	95		NITRIDE SEMICONDUCTOR LASER DEVICE	KOZAKI, TOKUYA
10888497	Not Issued	30	07/12/2004	Nitride semiconductor laser device and method of manufacturing the nitride semiconductor laser device	KOZAKI, TOKUYA
10978732	Not Issued	93	1	NITRIDE SEMICONDUCTOR DEVICE	KOZAKI, TOKUYA
11052835	Not Issued	41	02/09/2005	Nitride semiconductor growth method, nitride semiconductor substrate, and nitride semiconductor device	KOZAKI, TOKUYA
11287339	Not Issued	20	11/28/2005	Nitride semiconductor laser device	KOZAKI, TOKUYA

Course Amadham Immandam	Last Name	First Name	
Search Another: Inventor	Kozaki	Tokuya	Search.

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### **Inventor Name Search Result**

Your Search was:

Last Name = IWASA

First Name = NARUHITO

A 10 /0 //	Application# Patent# Status Date Filed Title Inventor Name						
					Inventor Name		
07970145	5306662	150	11/02/1992	METHOD OF MANUFACTURING P-TYPE COMPOUND SEMICONDUCTOR	IWASA, NARUHITO		
08153153	5578839	150	11/17/1993	LIGHT-EMITTING GALLIUM NITRIDE-BASED COMPOUND SEMICONDUCTOR DEVICE	IWASA, NARUHITO		
08180326	5468678	150	1	METHOD OF MANUFACTURING P-TYPE COMPOUND SEMICONDUCTOR	IWASA, NARUHITO		
08565101	5777350	150		NITRIDE SEMICONDUCTOR LIGHT-EMITTING DEVICE	IWASA, NARUHITO		
08661138	5747832	150	06/10/1996		IWASA, NARUHITO		
08661157	5734182	150	06/10/1996	LIGHT-EMITTING GALLIUM NITRIDE-BASED COMPOUND SEMICONDUCTOR DEVICE	IWASA, NARUHITO		
08705972	5880486	150	08/30/1996	LIGHT-EMITTING GALLIUM NITRIDE-BASED COMPOUND SEMICONDUCTOR DEVICE	IWASA, NARUHITO		
08743729	5959307	150	11/06/1996	NITRIDE SEMICONDUCTOR DEVICE	IWASA, NARUHITO		
09069240	Not Issued	164	I I	NITRIDE SEMICONDUCTOR LIGHT-EMITTING DEVICE	IWASA, NARUHITO		
09145972	6078063	150		LIGHT-EMITTING GALLIUM NITRIDE-BASED COMPOUND SEMICONDUCTOR DEVICE	IWASA, NARUHITO		
09202141	6153010	150		METHOD OF GROWING NITRIDE SEMICONDUCTORS, NITRIDE SEMICONDUCTOR SUBSTRATE AND NITRIDE	IWASA, NARUHITO		

				SEMICONDUCTOR DEVICE	
09293060	Not Issued	164	04/25/2000	NITRIDE SEMICONDUCTOR DEVICE	IWASA, NARUHITO
09300788	6215133	150	04/28/1999	LIGHT-EMITTING GALLIUM NITRIDE-BASED COMPOUND SEMICONDUCTOR DEVICE	IWASA, NARUHITO
09370170	Not Issued	164	08/09/1999	NITRIDE SEMICONDUCTOR LIGHT-EMITTING DEVICE	IWASA, NARUHITO
09516193	6469323	150	03/01/2000	LIGHT-EMITTING GALLIUM NITRIDE-BASED COMPOUND SEMICONDUCTOR DEVICE	IWASA, NARUHITO
09603437	Not Issued	168	06/23/2000	Nitride semiconductor growth method, nitride semiconductor substrate, and nitride semiconductor device	IWASA, NARUHITO
09809038	6900465	150	03/16/2001	NITRIDE SEMICONDUCTOR LIGHT-EMITTING DEVICE	IWASA, NARUHITO
09973817	6580099	150	10/11/2001	NITRIDE SEMICONDUCTOR LIGHT-EMITTING DEVICE	IWASA, NARUHITO
09986332	Not Issued	71	11/08/2001	Nitride semiconductor growth method, nitride semiconductor substrate, and nitride semiconductor device	IWASA, NARUHITO
10227834	6791103	150	08/27/2002	LIGHT-EMITTING GALLIUM NITRIDE-BASED COMPOUND SEMICONDUCTOR DEVICE	IWASA, NARUHITO
10229067	Not Issued	164		NITRIDE SEMICONDUCTOR WITH ACTIVE LAYER OF QUANTUM WELL STRUCTURE WITH INDDIUM- CONTAINING NITRIDE SEMICONDUCTOR	IWASA, NARUHITO
10261487	6756611	150	10/02/2002	NITRIDE SEMICONDUCTOR GROWTH METHOD, NITRIDE SEMICONDUCTOR SUBSTRATE, AND NITRIDE SEMICONDUCTOR DEVICE	IWASA, NARUHITO
10456475	Not Issued	161	06/09/2003	Light-emitting gallium nitride- based compound semiconductor device	IWASA, NARUHITO
10600833	6940103	150	06/23/2003	NITRIDE SEMICONDUCTOR GROWTH METHOD, NITRIDE SEMICONDUCTOR SUBSTRATE AND NITRIDE SEMICONDUCTOR DEVICE	IWASA, NARUHITO

10718652	Not Issued	41		Nitride semiconductor with active layer of quantum well structure with indium-containing nitride semiconductor	IWASA, NARUHITO
10801038	Not Issued	93	03/16/2004	NITRIDE SEMICONDUCTOR WITH ACTIVE LAYER OF QUANTUM WELL STRUCTURE WITH INDIUM- CONTAINING NITRIDE SEMICONDUCTOR	IWASA, NARUHITO
11052835	Not Issued	41		Nitride semiconductor growth method, nitride semiconductor substrate, and nitride semiconductor device	IWASA, NARUHITO

Carral Arradham Tarrana	Last Name	First Name	
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### **Inventor Name Search Result**

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Last Name = CHOCHO First Name = KAZUYUKI

Application#   Patent#   Status   Date Filed   Title	), JKI ),
NITRIDE SEMICONDUCTORS, NITRIDE SEMICONDUCTOR SUBSTRATE AND NITRIDE SEMICONDUCTOR SUBSTRATE AND NITRIDE SEMICONDUCTOR DEVICE  O9603437 Not Issued	), ),
Issued method, nitride semiconductor substrate, and nitride semiconductor device	
09880843   6627974   150   06/15/2001 NITRIDE SEMICONDUCTOR   CHOCHO	
SUBSTRATE AND METHOD FOR MANUFACTURING THE SAME, AND NITRIDE SEMICONDUCTOR DEVICE USING NITRIDE SEMICONDUCTOR SUBSTRATE	
Not   Issued   Semiconductor growth   Semic	′
10260442 6627520 150 10/01/2002 NITRIDE SEMICONDUCTOR SUBSTRATE AND METHOD FOR MANUFACTURING THE SAME, AND NITRIDE SEMICONDUCTOR DEVICE USING NITRIDE SEMICONDUCTOR SUBSTRATE	·
10261487 6756611 150 10/02/2002 NITRIDE SEMICONDUCTOR GROWTH METHOD, NITRIDE SEMICONDUCTOR SUBSTRATE, AND NITRIDE SEMICONDUCTOR DEVICE	

10389806	6861729	150	03/18/2003	CHOCHO, KAZUYUKI
10600833	6940103	150	06/23/2003	CHOCHO, KAZUYUKI
11052835	Not Issued	41		CHOCHO, KAZUYUKI

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